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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
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10/544,084

07/28/2005

Hiromoto II

KON-2020

9413

20311 7590 06/16/2009
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EXAMINER

TUROCZY, DAVID P

ART UNIT

PAPER NUMBER

1792

NOTIFICATION DATE

DELIVERY MODE

06/16/2009

ELECTRONIC

Please find below and/or attached an Office communication concerning this application or proceeding.

The time period for reply, if any, is set in the attached communication.

Notice of the Office communication was sent electronically on above-indicated "Notification Date" to the following e-mail address(es):

info@lmiplaw.com

Office Action Summary	Application No. 10/544,084	Applicant(s) II ET AL.	
	Examiner DAVID TUROCY	Art Unit 1792	

-- The MAILING DATE of this communication appears on the cover sheet with the correspondence address --

Period for Reply

A SHORTENED STATUTORY PERIOD FOR REPLY IS SET TO EXPIRE 3 MONTH(S) OR THIRTY (30) DAYS, WHICHEVER IS LONGER, FROM THE MAILING DATE OF THIS COMMUNICATION.

- Extensions of time may be available under the provisions of 37 CFR 1.136(a). In no event, however, may a reply be timely filed after SIX (6) MONTHS from the mailing date of this communication.
- If NO period for reply is specified above, the maximum statutory period will apply and will expire SIX (6) MONTHS from the mailing date of this communication.
- Failure to reply within the set or extended period for reply will, by statute, cause the application to become ABANDONED (35 U.S.C. § 133). Any reply received by the Office later than three months after the mailing date of this communication, even if timely filed, may reduce any earned patent term adjustment. See 37 CFR 1.704(b).

Status

- 1) ☒ Responsive to communication(s) filed on 18 May 2009.
- 2a) ☐ This action is **FINAL**. 2b) ☒ This action is non-final.
- 3) ☐ Since this application is in condition for allowance except for formal matters, prosecution as to the merits is closed in accordance with the practice under *Ex parte Quayle*, 1935 C.D. 11, 453 O.G. 213.

Disposition of Claims

- 4) ☒ Claim(s) 1-26 is/are pending in the application.
- 4a) Of the above claim(s) _____ is/are withdrawn from consideration.
- 5) ☐ Claim(s) _____ is/are allowed.
- 6) ☒ Claim(s) 1-26 is/are rejected.
- 7) ☐ Claim(s) _____ is/are objected to.
- 8) ☐ Claim(s) _____ are subject to restriction and/or election requirement.

Application Papers

- 9) ☐ The specification is objected to by the Examiner.
- 10) ☐ The drawing(s) filed on _____ is/are: a) ☐ accepted or b) ☐ objected to by the Examiner.
Applicant may not request that any objection to the drawing(s) be held in abeyance. See 37 CFR 1.85(a).
Replacement drawing sheet(s) including the correction is required if the drawing(s) is objected to. See 37 CFR 1.121(d).
- 11) ☐ The oath or declaration is objected to by the Examiner. Note the attached Office Action or form PTO-152.

Priority under 35 U.S.C. § 119

- 12) ☒ Acknowledgment is made of a claim for foreign priority under 35 U.S.C. § 119(a)-(d) or (f).
- a) ☐ All b) ☐ Some * c) ☐ None of:
1. ☐ Certified copies of the priority documents have been received.
2. ☐ Certified copies of the priority documents have been received in Application No. _____.
3. ☒ Copies of the certified copies of the priority documents have been received in this National Stage application from the International Bureau (PCT Rule 17.2(a)).

* See the attached detailed Office action for a list of the certified copies not received.

Attachment(s)

- | | |
|--|---|
| 1) <input checked="" type="checkbox"/> Notice of References Cited (PTO-892) | 4) <input type="checkbox"/> Interview Summary (PTO-413) |
| 2) <input type="checkbox"/> Notice of Draftsperson's Patent Drawing Review (PTO-948) | Paper No(s)/Mail Date. _____ |
| 3) <input type="checkbox"/> Information Disclosure Statement(s) (PTO/SB/08) | 5) <input type="checkbox"/> Notice of Informal Patent Application |
| Paper No(s)/Mail Date _____ | 6) <input type="checkbox"/> Other: _____ |

DETAILED ACTION

Continued Examination Under 37 CFR 1.114

1. A request for continued examination under 37 CFR 1.114, including the fee set forth in 37 CFR 1.17(e), was filed in this application after final rejection. Since this application is eligible for continued examination under 37 CFR 1.114, and the fee set forth in 37 CFR 1.17(e) has been timely paid, the finality of the previous Office action has been withdrawn pursuant to 37 CFR 1.114. Applicant's submission filed on 5/18/09 has been entered.

Response to Amendment

2. Applicant's amendments, filed 5/18/2009, have been fully considered and reviewed by the examiner. The examiner notes the amendment to independent claims and claim 4. Claims 1-26 remain pending in the instant application.

Response to Arguments

3. Applicant's arguments filed 5/18/2009 have been fully considered and reviewed by the examiner. The examiner notes the filing of the translation of JP 2003197799 and the subsequent disqualification of US '136 under 103(c) for the teachings of superposing the frequencies. The examiner cites US Patent 6089181 as a showing of superposing frequencies, see rejection that follows.

The US '136 reference however has not been disqualified for its entire teachings because it still qualifies under 102(a) for those teachings that are not perfected by the translation of the JP 2003197799 reference.

Claim Rejections - 35 USC § 103

4. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:

(a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negated by the manner in which the invention was made.

5. Claims 1-5, 12, 14, 15, 16 are rejected under 35 U.S.C. 103(a) as being unpatentable over US Patent 5290609 by Horiike et al., hereafter Horiike in view of US patent Publication 20030113479 by Fukuda et al., hereafter US '479 and further in view of US Patent Publication 20020043216 by Hwang et al., hereafter Hwang and US Patent 6089181 by Suemasa et al., hereafter Suemasa.

Horiike discloses a method of forming a metal oxide film on a substrate surface including the process of supplying a discharge, reducing, and reactive gas to deposit a first metal film by exposing the substrate to the excited reactive gas and thereafter providing an oxygen plasma to oxidize the metal film and thereby create a metal oxide film (Column 3, lines 1-15). Such plasma process would excite a discharge gas and oxygen gas and would transfer the energy to the gas in combination with the discharge gas, i.e. the reactive gas because such is inherent in a plasma process.

Horiike discloses vacuum processing and fails to disclose the frequency as claimed, however, US '479 discloses atmospheric pressure plasma has advantages over vacuum processing including elimination of expensive equipment and maintaining continuous processing (0004). US '479 discloses using a high frequency during the atmospheric plasma process to excite the gases (0245-0250). Therefore, it would have been obvious to one of ordinary skill in the art to have modified Horiike to use the atmospheric plasma apparatus and process parameters to deposit the metal oxide thin film by the multistep process because one would desire to reap the benefit of reduced expenses related to equipment costs.

Horiike in view of US '479 fails to disclose moving the substrate between the first and second discharge space; however, Hwang teaches improving a single chamber ALD process by including a rotating shaft with various chambers, each chamber dedicated to a single process gas and rotating the substrates between the chamber (figures, 0046-0050). Hwang also discloses using plasma enhanced gases in the process to deposit a metal oxide thin film (0005, 0030-0031). Hwang discloses repetitively moving the substrate between the processing areas to form a metal oxide film (0046-0050). Therefore, taking the references collectively, it would have been obvious to one of ordinary skill in the art at the time of the invention to have modified Horiike in view of US '479 to have rotated the substrates between the various processing zone with a reasonable expectation of successfully forming a ALD film and to reap the benefits as taught by Hwang.

Horiike in view of US '479 and Hwang fails to disclose superposing two frequencies to form the electric field, however, Suemasa discloses that such a technique for forming a film (note the disclosure exemplifies etching, but the plasma is discloses at column 1, lines 1-10 as being operable for deposition). Suemasa discloses the advantages to using superposing two frequencies over the traditional single frequency at column 1-2. Therefore, taking the references collectively, it would have been obvious to one of ordinary skill in the art at the time of the invention to have modified Horiike in view of US '479 and Hwang to use superposing of the two frequencies with a reasonable expectation of successfully forming a plasma for deposition and to reap the benefits of such a technique as taught by Suemasa. As for the requirement of two "high" frequencies, this is clearly a relative term with no clear scope and it is the examiners position that the frequencies of Suemasa can reasonably be considered high frequencies.

Additionally, all the claimed elements were known in the prior art and one skilled in the art could have combined the elements as claimed by known methods with no change in their respective functions, and the combination would have yielded predictable results to one of ordinary skill in the art at the time of the invention. See *KSR Int'l Inc. v. Teleflex Inc.*, 127 S Ct. 1727, 1741, 82 USPQ2d.

Claims 2-3: The limitations of these claims are discussed above.

Claim 4-5: In addition to above, US '479 at 0110 and US '136 at 0040 discloses the discharge gas of nitrogen of 50% or more in combination with hydrogen, a reducing gas.

Claims 8-11: Horiike discloses multiple plasma steps and thus the process as taught by Horiike in view of US '479, Hwang and US '136 would necessarily include a third and fourth frequency, a third and fourth electrode, and applying the third frequency and fourth frequency to the third and fourth electrode as claimed.

Claim 12, 14: Horiike discloses forming a metal oxide film using an organometallic zinc (column 4).

Claim 15: Horiike discloses repeating first and second a plurality of times to form a film (Column 3, lines 1-15).

Claim 16: Horiike discloses a thickness of less than 10 nm (column 6, lines 35-37).

6. Claims 6-11, 13, and 17-26 rejected under 35 U.S.C. 103(a) as being unpatentable over Horiike in view of US '479 and Hwang and further in view of US Patent Publication 2003/0232136 by Fukuda et al., hereinafter US '136.

Horiike in view of US '479 and Hwang and Suemasa discloses all that is discussed in the 35 USC 103(a) rejection above, however, the reference fails to disclose the plasma parameters as claimed, including the intensity relationship, and the power density. However, US '136 discloses a method of forming a plasma through a first and second electrode discloses providing the intensity relationship, power density, and frequency relationship as claimed (Column 9) results in forming a layer with high quality (Column 10, lines 1-4). Therefore, taking the references collectively it would have been obvious to one of ordinary skill in the art at the time of the invention to

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have modified Horiike in view of US '479 to provide the plasma process parameters as taught by US '136 to reap the benefits of the increased film quality.

Claim 6: US '136 discloses the feature as claimed (0054).

Claim 7: US '136 discloses the claims relationship between the frequency, intensity and power density as claimed (0046).

Claim 13: US '136 discloses forming a transparent conductive film as claimed (0201).

Claim 17-25: The prior art discloses each and every limitation of these claims are discussed above.

Claim 26: Horiike in view of US '479, Hwang and US '136 discloses a substrate with a film thereon.

Conclusion

7. The prior art made of record and not relied upon is considered pertinent to applicant's disclosure. US Patent Publication 20010028924 discloses supplying oxygen plasma to oxidize a metal film and performing multiple sequences to build a film of desired thickness (examples, 0036). US Patent 6200893 discloses supplying metal precursors and thereafter supplying hydrogen plasma to reduce to metal film and then an oxygen plasma to oxidize the metal film and repeating to form the desired film thickness (column 8-9).

Any inquiry concerning this communication or earlier communications from the examiner should be directed to DAVID TUROCY whose telephone number is (571)272-

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2940. The examiner can normally be reached on Monday-Friday 8:30-6:00, No 2nd Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Timothy Meeks can be reached on (571) 272-1423. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see <http://pair-direct.uspto.gov>. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free). If you would like assistance from a USPTO Customer Service Representative or access to the automated information system, call 800-786-9199 (IN USA OR CANADA) or 571-272-1000.

/David Turocy/

Examiner, Art Unit 1792